



### NPN GENERAL PURPOSE TRANSISTOR

VOLTAGE 30V/45V/65V POWER 625 mWatts

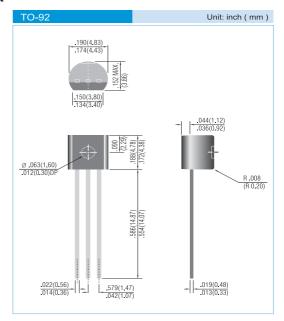
#### **FEATURES**

- NPN epitaxial silicon, planar design
- Collector current I<sub>c</sub> = 100mA
- Complimentary (PNP) device:BC556,BC557,BC558 Series
- Pb free product :99% Sn above can meet RoHS environment substance directive request

#### **MECHANICAL DATA**

- Case: TO-92
- Terminals: Solderable per MIL-STD-202, Method 208
- Approx Weight: 0.02grams
- Device Marking:

BC546A=546A	BC546B=546B	-
BC547A=547A	BC547B=547B	BC547C=547C
BC548A=548A	BC548B=548B	BC548C=548C



#### **ABSOLUTE MAXIMUM RATINGS**

PARAMETER		Symbol	Value	Units	
Collector - Emitter Voltage	BC546 BC547 BC548	V <sub>CEO</sub>	65 45 30	V	
Collector - Base Voltage	BC546 BC547 BC548	V <sub>CBO</sub>	80 50 30	V	
Emitter - Base Voltage	BC546 BC547 BC548	V <sub>EBO</sub>	6.0 6.0 5.0	V	
Collector Current - Continuous		I <sub>c</sub>	100	mA	
Max Power Dissipation		P <sub>TOT</sub>	625	mW	
Storage Temperature		T <sub>STG</sub>	-55 to 150	°C	
Junction Temperature		T <sub>J</sub>	-55 to 150	°C	

#### THERMAL CHARACTERISTICS

PARAMETER	Symbol	Value	Units
Thermal Resistance, Junction to Ambient	R <sub>eJA</sub>	200	°C/W





### ELECTRICAL CHARACTERISTICS (T<sub>J</sub>=25°C, unless otherwise noted)

PARAMETER		Symbol	MIN.	TYP.	MAX.	Units
Collector - Emitter Breakdown Voltage (I <sub>C</sub> =10mA, I <sub>B</sub> =0)	BC546A,B BC547A,B,C BC548A,B,C	V <sub>(BR)</sub> CEO	65 45 30	-	-	V
Collector - Base Breakdown Voltage $(I_c=10uA,\ I_e=0)$	BC546A,B BC547A,B,C BC548A,B,C	V <sub>(BR)</sub> CBO	80 50 30	-	-	V
Emitter - Base Breakdown Voltage $(I_e=10uA, I_c=0)$	BC546A,B BC547A,B,C BC548A,B,C	V <sub>(BR)</sub> EBO	6.0 6.0 5.0	-	-	V
Emitter-Base Cutoff Current (V <sub>EB</sub> =5V)		I <sub>EBO</sub>	-	-	100	nA
Collector-Base Cutoff Current(V <sub>CB</sub> =30V,I <sub>E</sub> =0)	T <sub>J</sub> =150°C	I <sub>cвo</sub>	-	-	15 5.0	nA uA
DC Current Gain (I <sub>c</sub> =10uA, V <sub>cE</sub> =5V)	BC546A,B BC547A,B,C BC548A,B,C	h <sub>ee</sub>		90 150 270	- - -	_
(I <sub>C</sub> =2.0mA, V <sub>CE</sub> =5V)	BC546A,B BC547A,B,C BC548A,B,C	· · FE	110 200 420	180 290 520	220 450 800	
ollector - Emitter Saturation Voltage	$(I_c = 10 \text{ mA}, I_B = 0.5 \text{ mA})$ $(I_c = 100 \text{ mA}, I_B = 5.0 \text{ mA})$	V CE(SAT)	-	-	0.25 0.6	V
Base - Emitter Saturation Voltage	$(I_c = 10 \text{ mA}, I_B = 0.5 \text{ mA})$ $(I_c = 100 \text{ mA}, I_B = 5.0 \text{ mA})$	V <sub>BE(SAT)</sub>	- -	0.7 0.9	- -	V
Base - Emitter Voltage	$(I_c = 2 \text{ mA V}_{cE} = 0.5 \text{ mA})$ $(I_c = 10 \text{ mA}, V_{CE} = 5.0 \text{ mA})$	V <sub>BE(SAT)</sub>	0.58	0.660	0.70 0.77	V
Collector - Base Capacitance	(V <sub>CB</sub> -10V,I <sub>E</sub> -0,f-1MH <sub>Z</sub> )	Ссво	-	-	4.5	pF

#### **LEGAL STATEMENT**

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#### ELECTRICAL CHARACTERISTICS CURVE BC546A,BC547A,BC548A ONLY

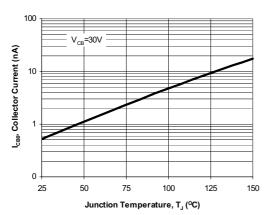


Fig. 1. Typical  $I_{CB0}$  vs.

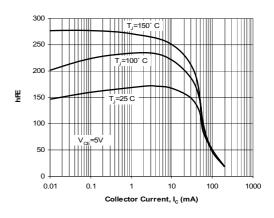


Fig. 2. Typical  $h_{FE}$  vs.

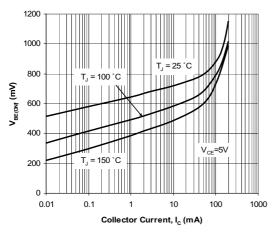


Fig. 3. Typical  $V_{\text{BE(ON)}}$  vs.

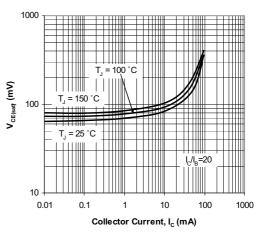


Fig. 4. Typical  $V_{CE(SAT)}$  vs.

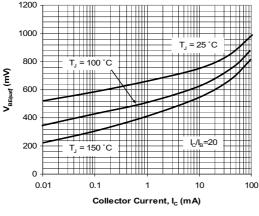


Fig. 5. Typical  $V_{BE(SAT)}$  vs.

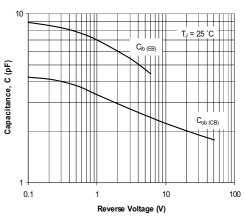


Fig. 6. Typical Capacitances vs.





#### ELECTRICAL CHARACTERISTICS CURVE BC546B,BC547B,BC548B ONLY

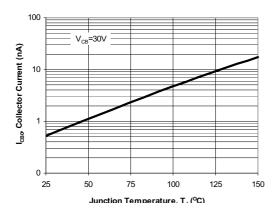


Fig. 1. Typical  $I_{CB0}$  vs. Junction Temperature

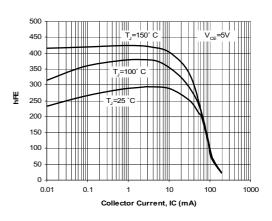


Fig. 2. Typical h<sub>FE</sub> vs. Collector Current

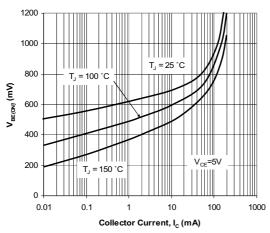


Fig. 3. Typical  $V_{BE(ON)}$  vs. Collector Current

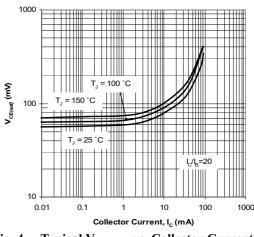


Fig. 4. Typical  $V_{CE(SAT)}$  vs. Collector Current

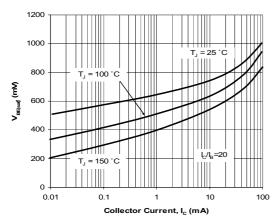


Fig. 5. Typical  $V_{BE(SAT)}$  vs. Collector Current

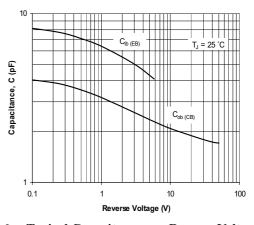


Fig. 6. Typical Capacitances vs. Reverse Voltage





#### ELECTRICAL CHARACTERISTICS CURVE BC547C, BC548C ONLY

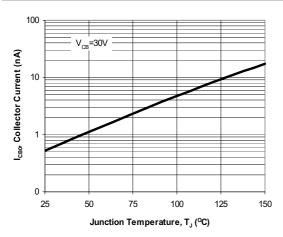


Fig. 1. Typical  $I_{CB0}$  vs. Junction

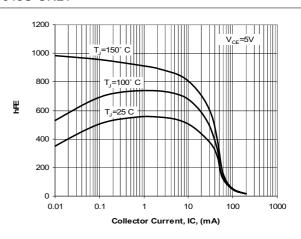


Fig. 2. Typical  $h_{FE}$  vs. Collector

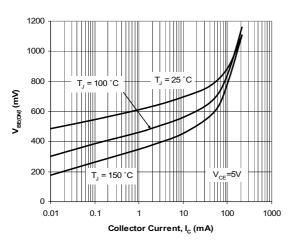


Fig. 3. Typical  $V_{BE(ON)}$  vs. Collector Current

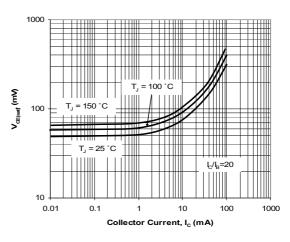


Fig. 4. Typical  $V_{CE(SAT)}$  vs. Collector

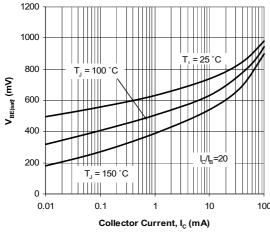


Fig. 5. Typical  $V_{BE(SAT)}$  vs. Collector

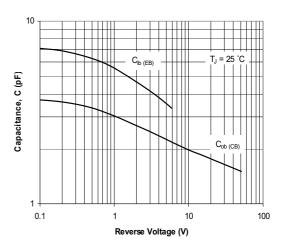


Fig. 6. Typical Capacitances vs. Reverse